TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSE TYPE (PCT PROCESS)

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HIGH VOLTAGE SWITCHING AND AMPLIFIER APPLICATIONS COLOR TV HORIZONTAL DRIVER APPLICATIONS COLOR TV CHROMA OUTPUT APPLICATIONS

 $: V_{(BR)CEO} = 300V$ High Voltage

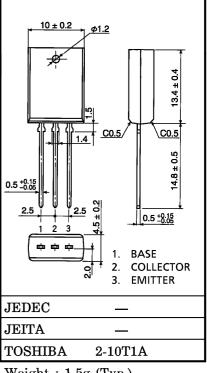
Small Collector Output Capacitance : $C_{ob}=3.0pF$ (Typ.)

Collector metal (Fin) is fully covered with mold resin.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	300	V
Collector-Emitter Voltage	v_{CEO}	300	V
Emitter-Base Voltage	$V_{ m EBO}$	7	V
Collector Current	$I_{\mathbf{C}}$	100	mA
Base Current	$I_{\mathbf{B}}$	50	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	1.8	w
Junction Temperature	$T_{ m j}$	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm

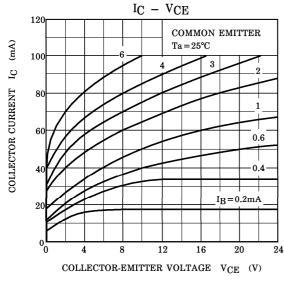


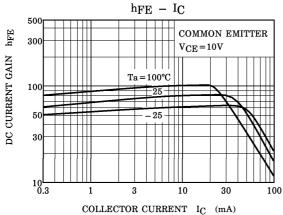
Weight: 1.5g (Typ.)

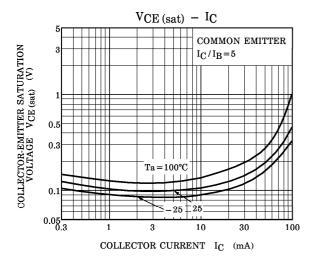
ELECTRICAL CHARACTERISTICS (Ta = 25°C Unless otherwise noted.)

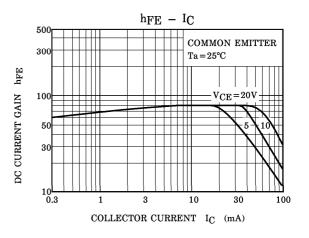
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 240V, I_{E} = 0$	_		1.0	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=7V, I_{C}=0$	_	_	1.0	μ A
DC Current Gain	hFE (1)	$V_{\text{CE}} = 10V$, $I_{\text{C}} = 4\text{mA}$	20	_	_	
	h _{FE} (2)	$V_{CE}=10V$, $I_{C}=20mA$	30	_	200	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{C}=10$ mA, $I_{B}=1$ mA	_	_	1.0	V
Base-Emitter Saturation Voltage	V _{BE (sat)}	$I_{C}=10$ mA, $I_{B}=1$ mA	_	_	1.0	V
Transition Frequency	$ m f_{T}$	$V_{\text{CE}} = 10V$, $I_{\text{C}} = 20\text{mA}$	50	70	_	MHz
Collector Output Capacitance	$\mathrm{C_{ob}}$	$V_{CB} = 20V, I_{E} = 0, f = 1MHz$	_	3.0	_	pF

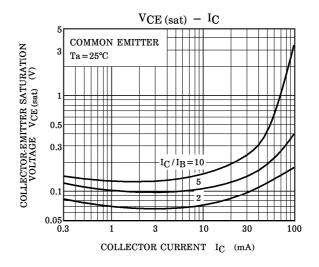
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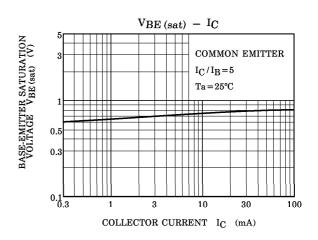




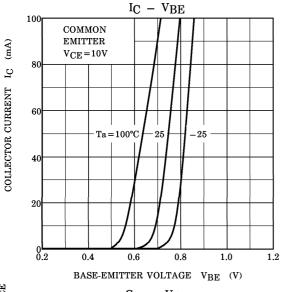


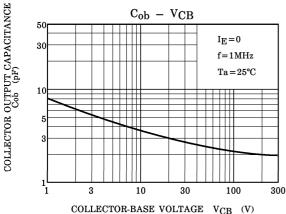


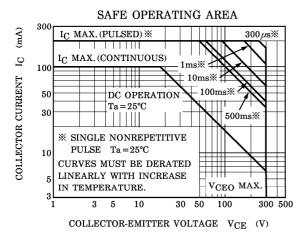


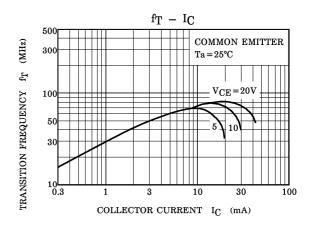


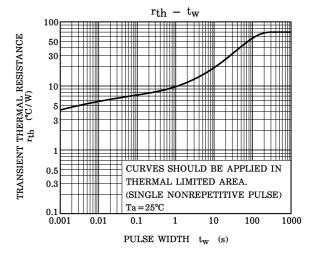
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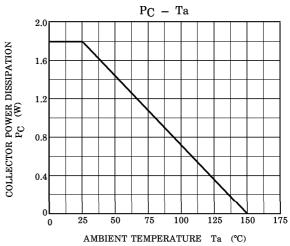












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